

MT47H512M4THN-25E:M



Part Number: [MT47H512M4THN-25E:M](#)

Manufacturer: [Micron Technology](#)

Description: IC DRAM 2G PARALLEL 400MHZ

Data sheet:  [MT47H512M4](#), [MT47H256M8](#)

RoHs Status: Lead free / RoHS Compliant


















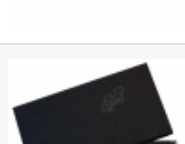


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PRODUCT PARAMETER			
Part Number	MT47H512M4THN-25E:M	Manufacturer	Micron Technology
Description	IC DRAM 2G PARALLEL 400MHZ	Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Quantity Available	3979 pcs	Data sheet	MT47H512M4 , MT47H256M8
Category	Integrated Circuits (ICs)	Write Cycle Time - Word, Page	15ns
Voltage - Supply	1.7 V ~ 1.9 V	Technology	SDRAM - DDR2
Series	-	Operating Temperature	0°C ~ 85°C (TC)
Moisture Sensitivity Level (MSL)	3 (168 Hours)	Memory Type	Volatile
Memory Size	2Gb (512M x 4)	Memory Interface	Parallel
Memory Format	DRAM	Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Detailed Description	SDRAM - DDR2 Memory IC 2Gb (512M x 4) Parallel 400MHz 400ps	Clock Frequency	400MHz
Access Time	400ps		
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	Part#: MT47H512M4THN-3:E TR Description: IC DRAM 2G PARALLEL 63FBGA	Manufacturers: Micron Technology	<div>RFQ</div>
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